



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
2014	0.9Ω @V _{GS} = -10V	-0.55A
-30V	1.7Ω @V _{GS} = -4.5V	-0.4A

Description and Applications

This MOSFET is designed to minimize on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- Power-management functions
- **DC-DC** converters

Features and Benefits

- Low On-Resistance .
- Low Input Capacitance
- Fast Switching Speed
- **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP31D7LDWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

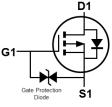
https://www.diodes.com/quality/product-definitions/

Mechanical Data

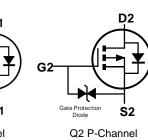
- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)

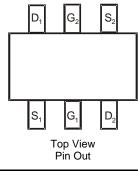






Q1 P-Channel





Ordering Information (Note 4)

Orderable Part Number	Backage	Packing		
Orderable Part Number	Package	Qty.	Carrier	
DMP31D7LDWQ-7	SOT363	3000	Tape & Reel	
DMP31D7LDWQ-13	SOT363	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

	\square	-
AN2	YM	
MY	SNA	
		-

AN2 = Product Type Marking Code YM = Date Code Marking

Y or \overline{Y} or \underline{Y} = Year (ex: L = 2024)

M = Month (ex: 9 = September)

Date Code Key												
Year	2019	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	G	-	L	М	N	Р	R	S	Т	U	V	W
	1	1	1	1		1						_
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

DUAL P-CHANNEL ENHANCEMENT MODE MOSFET



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	Vdss	-30	V
Gate-Source Voltage	Vgss	±20	V
Continuous Drain Current (Note 6) V _{GS} = -10V	ID	-0.55 -0.44	А
Maximum Continuous Body Diode Forward Current (Note 6)	ls	-0.38	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	-2.4	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.29	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	433	°C/W	
Total Power Dissipation (Note 6)		PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	301	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics – P Channel (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	—	V	Vgs = 0, Id = -250µA
Zero Gate Voltage Drain Current	IDSS		_	-1	μA	Vds = -24V, Vgs = 0
Gate-Source Leakage	Igss	_	_	±10	μA	$V_{GS} = \pm 16V, V_{DS} = 0$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	-1	-2.2	-2.6	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Deserve		0.5	0.9	Ω	Vgs = -10V, ID = -0.42A
	Rds(on)		0.78	1.7	12	Vgs = -4.5V, ID = -0.2A
Diode Forward Voltage	V _{SD}	_	-0.8	-1.2	V	$V_{GS} = 0, I_{S} = -0.23A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	19	_	pF	
Output Capacitance	Coss	_	16	_	pF	VDS = -15V, VGS = 0, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	3	_	pF	
Gate Resistance	Rg	_	729	_	Ω	$V_{DS} = V_{GS} = 0$, f = 1.0MHz
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	0.36	_	nC	
Total Gate Charge (V _{GS} = -10V)	Qg	_	0.8	_	nC	
Gate-Source Charge	Q _{gs}	_	0.1	_	nC	VDS = -10V, ID = -0.24A
Gate-Drain Charge	Q _{gd}	_	0.1	_	nC	7
Turn-On Delay Time	td(on)	_	30		ns	
Turn-On Rise Time	tR		74	_	ns	Vgs = -10V, Vdd = -15V,
Turn-Off Delay Time	tD(OFF)	_	28	—	ns	I _D = -0.5A, R _G = 1Ω
Turn-Off Fall Time	tF	_	31	_	ns	1

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1in square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

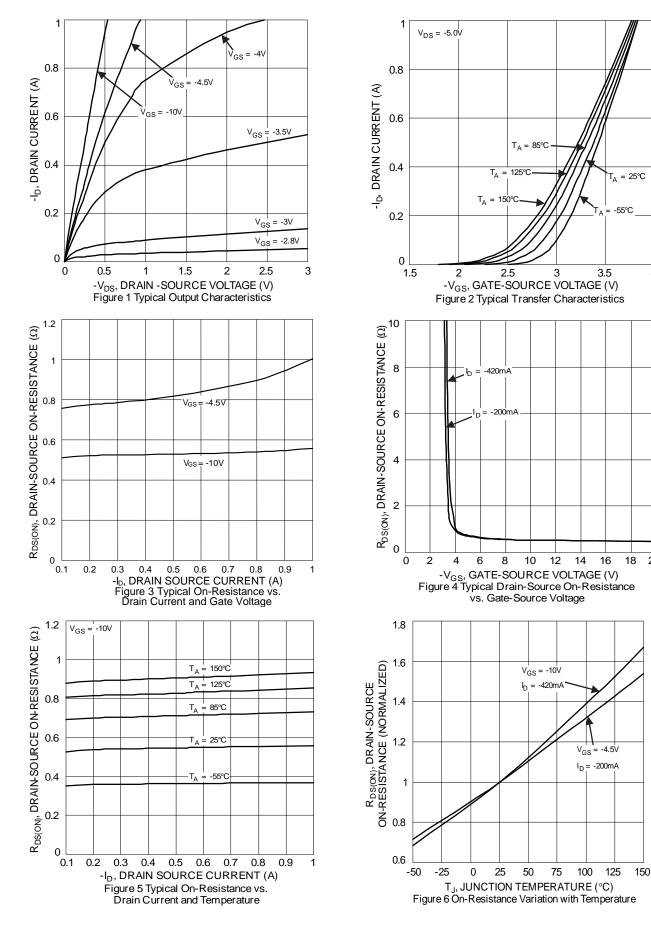
8. Guaranteed by design. Not subject to product testing.



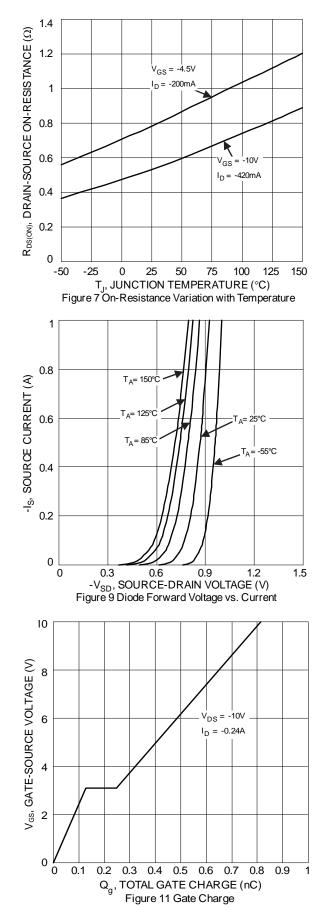
DMP31D7LDWQ

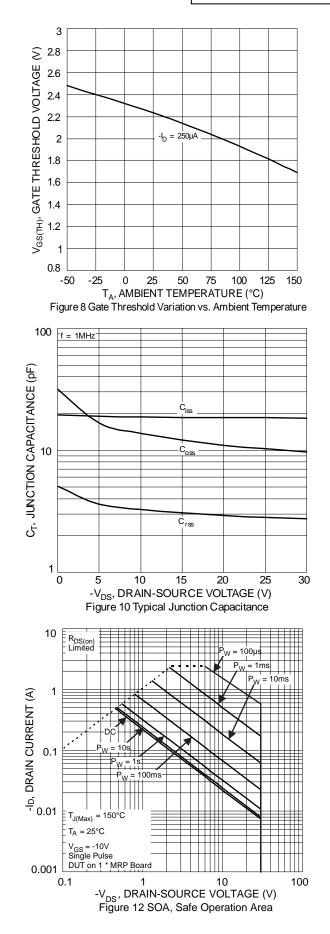
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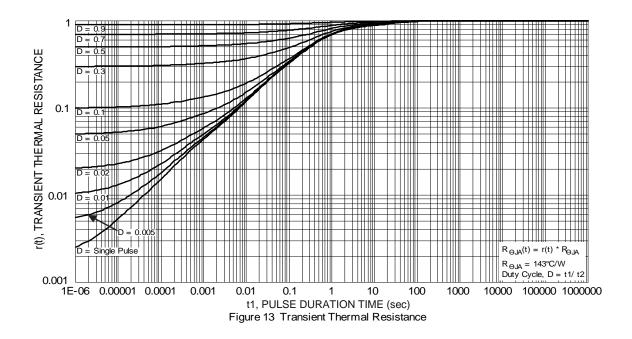






DMP31D7LDWQ Document number: DS42358 Rev. 4 - 2

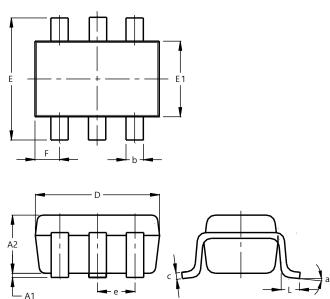






Package Outline Dimensions

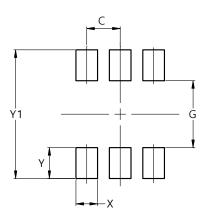
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.10	0.30	0.25					
с	0.10	0.22	0.11					
D	1.80	2.20	2.15					
ш	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
e	C).650 E	SC					
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All I	Dimen	sions	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT363

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Y	0.600
Y1	2.500

SOT363



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